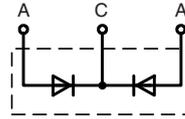


# Power Schottky Rectifier with common cathode

$I_{FAV} = 15 \text{ A}$   
 $V_{RRM} = 100 \text{ V}$   
 $V_F = 0.64 \text{ V}$

| $V_{RSM}$ | $V_{RRM}$ | Type         |
|-----------|-----------|--------------|
| V         | V         |              |
| 100       | 100       | DSSK 28-01AS |


**TO-263 AB**


A = Anode, C = Cathode, TAB = Cathode

| Symbol         | Conditions   | Maximum Ratings |                  |
|----------------|--|-----------------|------------------|
| $I_{FRMS}$     |  | 35              | A                |
| $I_{FAV}$      | $T_C = 160^\circ\text{C}$ ; rectangular, $d = 0.5$   | 2x15            | A                |
| $I_{FSM}$      | $T_{VJ} = 45^\circ\text{C}$ ; $t_p = 10 \text{ ms}$ (50 Hz), sinev                             | 230             | A                |
| $E_{AS}$       | $I_{AS} = 10 \text{ A}$ ; $L = 100 \mu\text{H}$ ; $T_{VJ} = 25^\circ\text{C}$ ; non repetitive | 5               | mJ               |
| $I_{AR}$       | $V_A = 1.5 \cdot V_{RRM}$ typ.; $f = 10 \text{ kHz}$ ; repetitive                              | 1               | A                |
| $(dv/dt)_{cr}$ |  | 5000            | V/ $\mu\text{s}$ |
| $T_{VJ}$       |  | -55...+175      | $^\circ\text{C}$ |
| $T_{VJM}$      |  | 175             | $^\circ\text{C}$ |
| $T_{stg}$      |  | -55...+150      | $^\circ\text{C}$ |
| $P_{tot}$      | $T_C = 25^\circ\text{C}$   | 105             | W                |
| $F_C$          | mounting force   | 20...60         | N                |
| Weight         | typical  | 2               | g                |

### Features

- International standard package
- Very low  $V_F$
- Extremely low switching losses
- Low  $I_{RM}$ -values
- Epoxy meets UL 94V-0

### Applications

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

### Advantages

- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses

| Symbol     | Conditions  | Characteristic Values |        |
|------------|---|-----------------------|--------|
|            |   | typ.                  | max.   |
| $I_R$ ①    | $V_R = V_{RRM}$ ; $T_{VJ} = 25^\circ\text{C}$       |                       | 0.5 mA |
|            | $V_R = V_{RRM}$ ; $T_{VJ} = 125^\circ\text{C}$      |                       | 5 mA   |
| $V_F$      | $I_F = 15 \text{ A}$ ; $T_{VJ} = 125^\circ\text{C}$ |                       | 0.64 V |
|            | $I_F = 15 \text{ A}$ ; $T_{VJ} = 25^\circ\text{C}$  |                       | 0.82 V |
|            | $I_F = 30 \text{ A}$ ; $T_{VJ} = 125^\circ\text{C}$ |                       | 0.78 V |
| $R_{thJC}$ |   | 1.4                   | K/W    |

Pulse test: Pulse Width = 5 ms, Duty Cycle < 2.0 %

Data according to IEC 60747 and per diode unless otherwise specified

Dimensions see Outlines.pdf

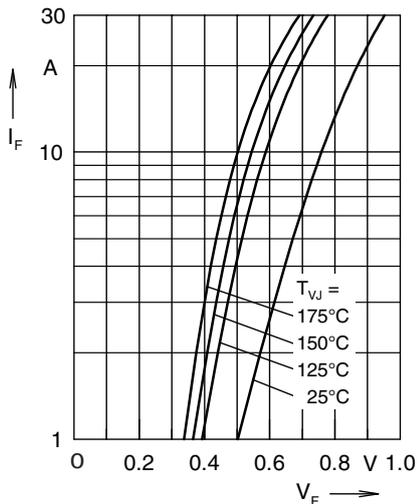


Fig. 1 Max. forward voltage drop characteristics

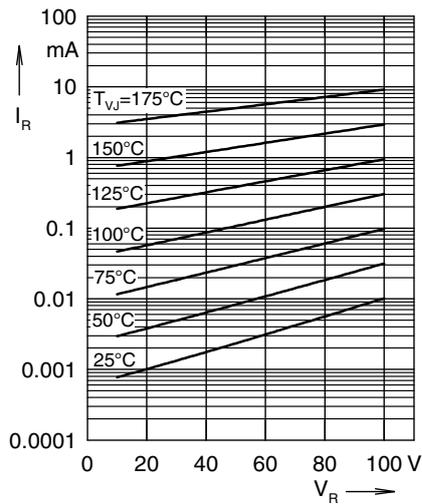


Fig. 2 Typ. reverse current  $I_R$  vs. reverse voltage  $V_R$

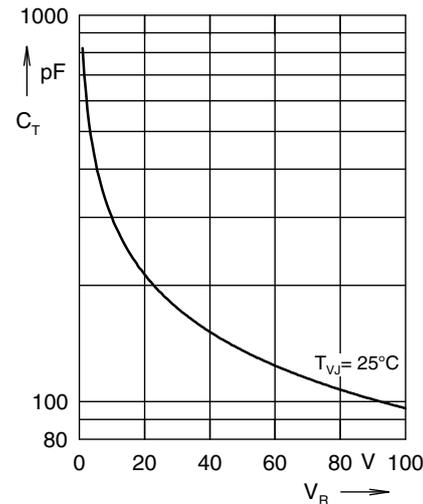


Fig. 3 Typ. junction capacitance  $C_T$  versus reverse voltage  $V_R$

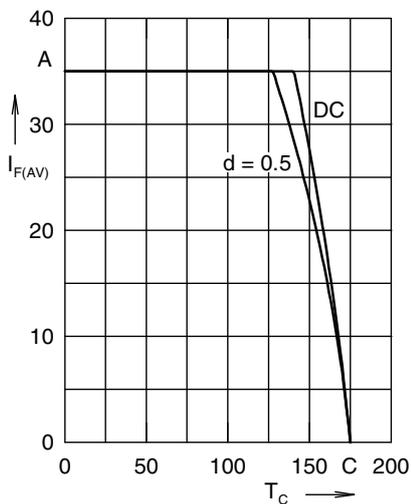


Fig. 4 Avg. forward current  $I_{F(AV)}$  vs. case temperature  $T_C$

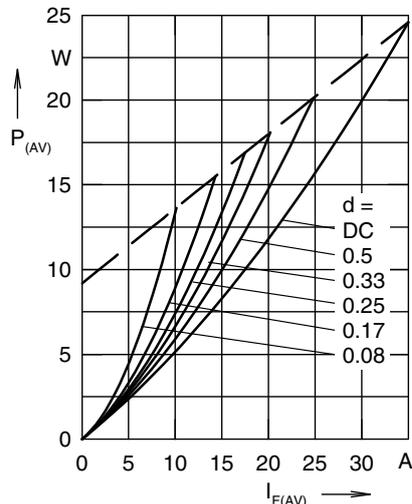


Fig. 5 Forward power loss characteristics

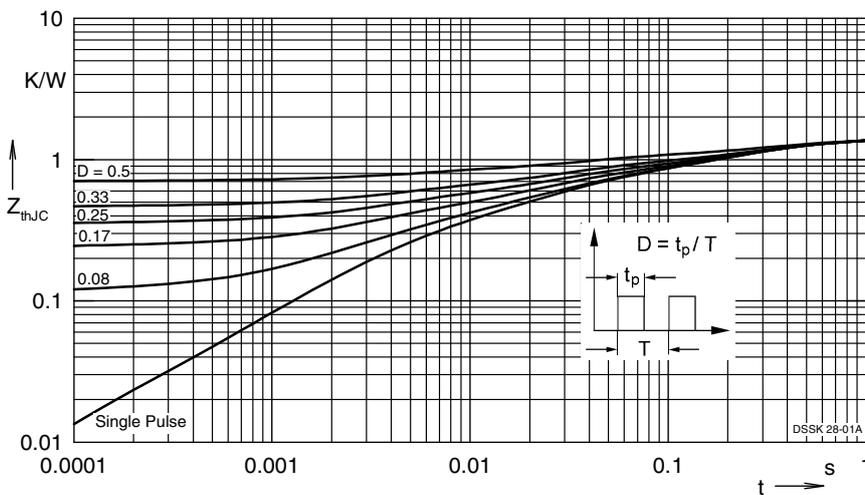


Fig. 6 Transient thermal impedance junction to case at various duty cycles

Note: All curves are per diode

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